ISSN 2277 – 6362 International Journal of Luminescence and Applications Vol.1 (II)

Photoluminescence study of LaPO₄ and Ce, Eu & Tb Phosphor

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Abstract

The present paper reports the Photoluminescence (PL) of the LaPO₄ phosphor doped with Ce, Eu and Tb with 0.5 mole percentage. The phosphors were synthesized using the standard solid state reaction technique and ground using mortar and pestle, fired at 1200° C for 4 hour in a muffle furnace. The crystallinity and phase purity of the phosphor was confirmed by XRD studies. The Photoluminescence properties of the materials were studied using Spectrofluorophotometer at room temperature. Under the excitation of 254nm wavelength, PL emission of doped LaPO₄ phosphor shows peaks at 381, 415, 437, 457, 473, 488, 545, 589, 596, 614 and 622nm with good intensity.

Phosphors are widely used in displays and lighting devices. The useful applications of rare earth element compounds, especially lanthanide phosphate doped with rare earth elements have wide applications in display industry[1-2]. We adopted the standard solid state reaction technique to prepare LaPO₄ with good morphologies and fine crystal structures; and its emission and intensity of luminescence were also present studied. The paper reports the Photoluminescence (PL) of the LaPO₄ phosphor doped with Ce, Eu and Tb rare-earth ions with 0.5% concentration.

1.1 EXPERIMENTAL:-

LaPO₄ phosphor doped with Ce, Eu and Tb rare-earth ions with concentration of 0.5% were prepared using solid state synthesis method. Stoichiometric proportions of raw materials, (La_2O_3) , $[(NH_4)_2 H PO_4)$, (Ce_2O_3) , (Eu_2O_3) , (Tb_4O_7) were grinded in an agate motor and mixed and compressed into a crucible and heated at 1200°C for 4 hours. The prepared samples were again powdered for taking the measurements. The XRD's were obtained using XPERT-PRO at NCL Pune and the excitation & emission spectra were recorded at room using (SHIMADZU, make temperature Spectroflurophotometer RF - 5301 PC) using Xenon lamp as excitation source at display research Lab., Department of Applied Physics, Faculty of Technology and Engg., M.S.University. Baroda.. The emission and excitation slit were kept at 1.5 nm.

1.2 RESULTS AND DISCUSSIONS:-

X-ray diffraction study (Phase purity and structure):-



The crystallinity and phase purity of the product were firstly examined by XRD analysis. Fig.1 & Fig.2. Shows the typical X-ray diffraction (XRD) patterns of synthesized samples of pure LaPO₄ and LaPO₄ dopped with Ce, Eu, and Tb. As shown XRD patterns of nanocrystals are in good agreement with the values from JCPDS no.35-7310f LaPO₄, which shows that all the products are monazite LaPO₄ with monoclinic

ISSN 2277 – 6362 International Journal of Luminescence and Applications Vol.1 (II)

structure. All diffraction patterns were obtained using CuK α radiation ($\lambda = 1.540598 \text{ A}^0$) at 40 kv and 30 mA, and divergence slit fixed at 1.52 mm. Measurements were made from $2\theta = 10^0$ to 80^0 with steps of 0.008356^0 .

When crystallites are less than approximately 100 nm in size, appreciable broadening in X-ray diffraction lines occurs. The crystallite size of powder sample were calculated by using Scherer equation $D=0.9 \lambda / \beta cos\theta$

Where β represents full width at half maximum (FWHM) of XRD lines

 λ = Wavelength of the X-rays.(0.154 nm in the present case)

 θ = Braggs angle of the XRD peak.

The average crystallite size of $LaPO_4$ phosphors is 62 nm and when doped with Ce, Eu, Tb dopants, the crystallite size becomes 75 nm.

Scanning Electron Microscope (SEM):-

Fig.3 Shows SEM image of pure $LaPO_4$ at $1200^{\circ}C$ for 4 hours and Fig.4. Shows SEM image of LaPO4: Ce, Eu, Tb. This appears to irregular shape having an average basal diameter of 500 nm and length of 1.5 μ m.



Fig.3 SEM Image of LaPO₄



Fig.4. SEM Image of LaPO₄: Ce, Eu, Tb

1.2 (A) Photo luminescence study:

Fig.5. shows the excitation spectra of undoped LaPO₄ phosphor and fig.6 shows emission spectra of undoped LaPO4. The PL emission of pure LaPO4 was observed at 470 nm wavelength. Fig.7. shows the PL emission of doped LaPO₄: Ce, Eu, Tb phosphor under the excitation of 254 nm wavelength. The phosphor shows the peaks at 381, 415, 437, 457, 473, 488, 545, 589, 596, 614 and 622 nm with good intensity. In the trivalent rare earth ions, the luminescence arises mainly due to transactions within the 4 f shell. The efficiency of emission depends on the number of electrons in the 4f shell. The Tb^{3+} ion has 8 electrons in the 4f shell, which can be excited in the 4f-5d excitation band [7]. The electron in the excited $4f^7$ - 5d state remains at the surface of the ion and comes under the strong influence of the crystal field resulting in the splitting of the excitation band. The excitation Spectra thus has multiple peaks. The excited ion in the $4f^7$ - 5D State decays stepwise from this state to the luminescent levels $5D4f_3$ or $5d4f_4$ by giving up phonons to the lattice [8]. Luminescence emission occurs from either of these states, with the ion returning to the ground state. The emission line in the green region lying at 545 nm is due to the transition $5D_4$ -7F₆, 585 nm due to ${}^{5}D_{4}$ - ${}^{7}F_{4}$ and 620 nm due to ${}^{5}D_{4}$ - ${}^{7}F_{5}$. There are in fact multiple emission lines at each of these due to the crystal field splitting of the ground state of the emitting ions [8].





1.3 CONCLUSIONS

LaPO4:Ce,Eu,Tb phosphor were prepared using solid state synthesis method are successfully synthesized. The main peak in XRD pattern was found around 28.6° corresponding to a d- value of about $3.13A^{\circ}$, followed by other less intense peaks corresponds to the monoclinic system of crystal structure of Lanthanum Phosphate. The LaPO₄: Ce, Eu, Tb phosphors can be easily applied in various types of lamp and display due to its good PL performance. In this regard, our target product is a very promising phosphor.

1.4 ACKNOLEDGEMENT

The authors are thankful to Dr. U.V. Bhosle, Principal, MCT's Rajiv Gandhi Institute of Technology, Andheri, Mumbai, for continuous encouragement.

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